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· · ·	Application No.	Applicant(s)	<u> </u>
Notice of Allowability	09/938,435	WON ET AL.	
	Examiner	Art Unit	
		·	
	Monique R Jackson	1773	
The MAILING DATE of this communication claims being allowable, PROSECUTION ON THE MERI rewith (or previously mailed), a Notice of Allowance (PTOTICE OF ALLOWABILITY IS NOT A GRANT OF PATE the Office or upon petition by the applicant. See 37 CFR	ITS IS (OR REMAINS) CLOSED in DL-85) or other appropriate commu ENT RIGHTS. This application is s	n this application. If not included unication will be mailed in due course.	
☐ This communication is responsive to <i>Amendment file</i>	ad 11/19/03		
The allowed claim(s) is/are <u>1-13 and 25-38</u> .	<del>70 1 11 10 00</del> .		
The drawings filed on 8/23/01 are accepted by the E	xaminer		
Acknowledgment is made of a claim for foreign price		or (f).	
a) All b) Some* c) None of the:	, , , , , , , , , , , , , , , , , , ,		
1. ☐ Certified copies of the priority document	s have been received.		
2. Certified copies of the priority document		in No.	
3. Copies of the certified copies of the prior			the
International Bureau (PCT Rule 17.2)	Ţ	Till tillo ilditoridi otago appiloatio	uic
* Certified copies not received:	(4)).		
Acknowledgment is made of a claim for domestic price	ority under 35 U.S.C. & 119(e) (to :	a provisional application) since a speci	fic
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A SUBSTITUTE OATH OR DECLARATION must be INFORMAL PATENT APPLICATION (PTO-152) which			)F
CORRECTED DRAWINGS ( as "replacement sheets	s") must be submitted.		
(a) I including changes required by the Notice of Draf	ftsperson's Patent Drawing Review	v ( PTO-948) attached	
1) 🗌 hereto or 2) 🔲 to Paper No			
(b) ☐ including changes required by the proposed draw	wing correction filed, which	h has been approved by the Examiner.	
(c) ☐ including changes required by the attached Example 1.	miner's Amendment / Comment or	in the Office action of Paper No	<b></b>
Identifying indicia such as the application number (see 37 each sheet. Replacement sheet(s) should be labeled as su			
. ☐ DEPOSIT OF and/or INFORMATION about the ttached Examiner's comment regarding REQUIREMENT F			
ttachment(s)	F□ Notice of Info	ormal Patent Application (PTO-152)	
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☐ Notice of References Cited (PTO-892)		mmary (PTO-413), Paper No	
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ttachment(s)  Notice of References Cited (PTO-892)  Notice of Draftperson's Patent Drawing Review (PTO-9) Information Disclosure Statements (PTO-1449 or PTO/Paper No.	6 Interview Sur /SB/08), 7 Examiner's A	mendment/Comment	
<ul> <li>Notice of References Cited (PTO-892)</li> <li>Notice of Draftperson's Patent Drawing Review (PTO-9</li> <li>Information Disclosure Statements (PTO-1449 or PTO/</li> </ul>	6 Interview Sur /SB/08), 7 Examiner's A		

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## **REASONS FOR ALLOWANCE**

1. The following is an examiner's statement of reasons for allowance: The closest prior art Goto et al teaches deposition of TEOS oxide using pulsed RF plasma wherein a TEOS precursor is deposited on a silicon dioxide substrate using a PECVD process to produce an organosilicate film on the substrate such that the thickness uniformity of the film is less than 10% and wherein the process includes inputting He, Oxygen and TEOS into a PECVD chamber and applying RF energy to generate a plasma utilizing standard TEOS conditions wherein He is supplied at 100 sccm, Oxygen at 350 sccm, and TEOS at 185 sccm, at a temperature of 400°C. However, as stated by the Applicant, Goto et al was commonly owned and assigned to the same entity as the instant invention at the time of the invention and hence has been disqualified as a prior art reference under 35 U.S.C. 103(c).

Any comments considered necessary by applicant must be submitted no later than the payment of the issue fee and, to avoid processing delays, should preferably accompany the issue fee. Such submissions should be clearly labeled "Comments on Statement of Reasons for Allowance."

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Monique R Jackson whose telephone number is 571-272-1508. The examiner can normally be reached on Mondays-Thursdays, 8:00AM-4:30PM.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Paul J Thibodeau can be reached on 571-272-1516. The fax phone number for the organization where this application or proceeding is assigned is (703) 872-9306.

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Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is 571-272-1700.

Monique R. Jackson

Primary Examiner

Technology Center 1700

January 22, 2004